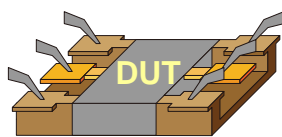


# Multi-Line De-Embedding Technique for Millimeter-Wave Circuit Design

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## 1 Background

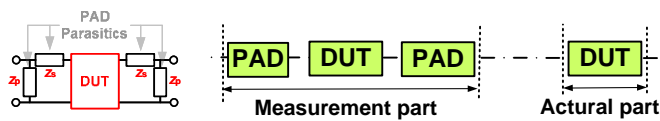
- On-wafer measurement needs contact pads
  - Measurement data includes the device under test (DUT) and the pad parasitic components.
  - At millimeter wave (MMW), parasitic components are not negligible.



Device Measurement Contact Pads

### De-Embedding

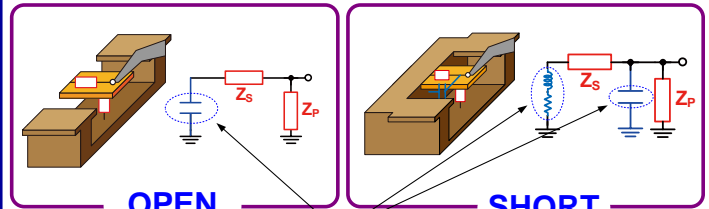
- Remove parasitic components from measurement data



Parasitics of pad De-embedding process

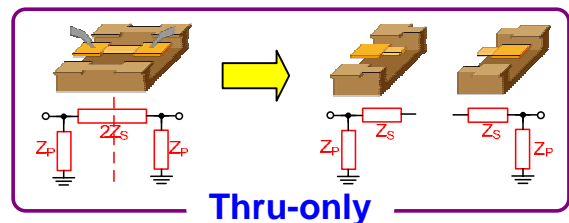
## 2 Conventional de-embedding method

### Open-short de-embedding method



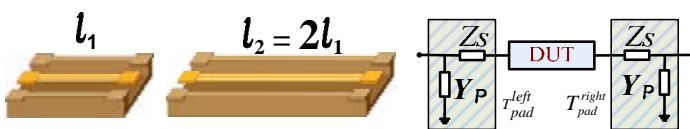
- Difficult to get the ideal patterns at high frequency (MMW)

### Thru-only de-embedding method

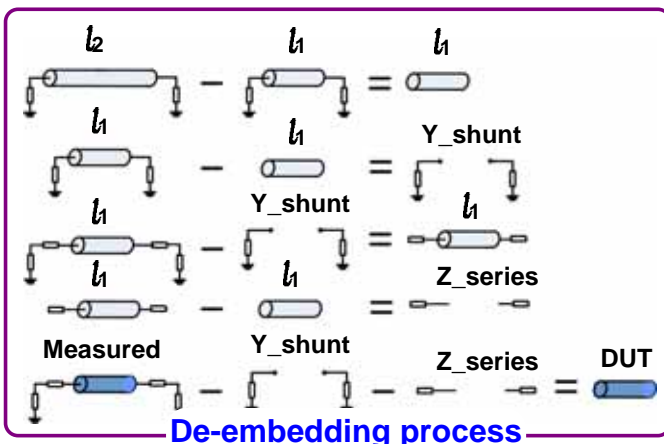


- The through-line is required to be very short
- Probe coupling

## 3 Proposed de-embedding method



Two transmission lines Pad model



De-embedding process

- Based on distributed-constant approach
- Doesn't need "Short" or "Short-Line"

$$Y_{shunt} = \frac{Y_{pad}(1,1) + Y_{pad}(2,1) + Y_{pad}(1,2) + Y_{pad}(2,2)}{2}$$

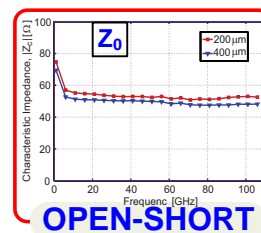
**Shunt Impedance**

## 4 Results and Conclusion

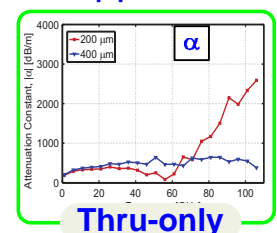
- De-embedding of different-length TLs (200μm and 400μm)
- Compare  $Z_0$ ,  $\alpha$ ,  $\beta$



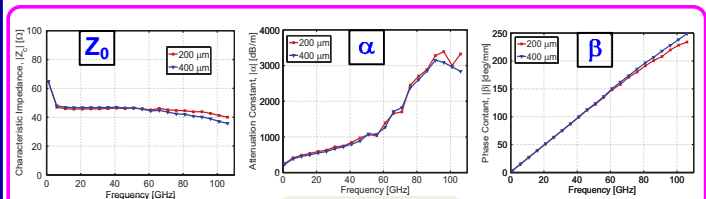
Chip photo



OPEN-SHORT



Thru-only



Proposed

- Mismatched in  $Z_0$  when using open-short
- Thru-only gives a large difference in  $\alpha$
- Up to 80GHz, the error in  $Z_0$ ,  $\alpha$ ,  $\beta$  is less than 5.5%, 2% and 3% respectively by using the proposed method.